

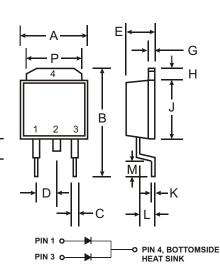
## 10A SURFACE MOUNT DUAL SCHOTTKY BARRIER RECTIFIER

### **Features**

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- Very Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, OR'ing, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

## **Mechanical Data**

- Case: DPAK Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: See Sheet 2
- Weight: 0.4 grams (approx.)
- Ordering Information, See Below



DPAK					
Dim	Min	Max			
Α	6.3	6.7			
В	_	10			
С	0.3	0.8			
D	2.3 Nominal				
E	2.1	2.5			
G	0.4	0.6			
Н	1.2	1.6			
J	5.3	5.7			
K	0.5 Nominal				
L	1.3	1.8			
M	1.0	_			
Р	5.1	5.5			
All Dimensions in mm					

#### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	40	٧
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Rectified Output Current Per Element (See Figure 4) Per Package	Io	5 10	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load Per Package (JEDEC Method)	I <sub>FSM</sub>	75	А
Typical Thermal Resistance Junction to Case Per Element (Note 1)	ReJC	2.43	°C/W
Voltage Rate of Change @ V <sub>R</sub> = 35V, T <sub>j</sub> = 25°C	dv/dt	10,000	V/μs
Operating Temperature Range	Tj	-55 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

1. Device mounted on PC board with 14mm<sup>2</sup> (.013mm thick) copper pad areas. Notes:

# **Ordering Information** (Note 2)

Device	Packaging	Shipping
MBRD1040CT-T	DPAK	2500/Tape & Reel

2. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf. Notes:



### Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V <sub>(BR)R</sub>	40	_	_	V	$I_R = 500 \mu A$
Forward Voltage (Note 2)	V <sub>FM</sub>		0.46 — 0.53	0.48 0.41 0.57 0.55	V	$\begin{array}{l} I_F = 5A,  T_S =  25^{\circ}C \\ I_F = 5A,  T_S =  100^{\circ}C \\ I_F = 10A,  T_S =  25^{\circ}C \\ I_F = 10A,  T_S =  100^{\circ}C \end{array}$
Peak Reverse Current (Note 2)	I <sub>RM</sub>		60  15 	150 10 80 3	μΑ mA μΑ mA	$\begin{array}{l} V_R = 35 V, \ T_j = 25^{\circ} C \\ V_R = 35 V, \ T_j = 100^{\circ} C \\ V_R = 17.5 V, \ T_j = 25^{\circ} C \\ V_R = 17.5 V, \ T_j = 100^{\circ} C \end{array}$
Typical Junction Capacitance	Cj	_	500		pF	f = 1.0MHz, V <sub>R</sub> = 4.0V DC

Notes: 1. Device mounted on PC board with 14mm<sup>2</sup> (.013mm thick) copper pad areas.

2. Short duration test pulse used to minimize self-heating effect.

## **Marking Information**



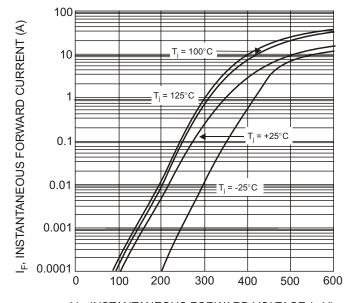
MBRD1040CT = Product type marking code

Office = Manufacturers' code marking

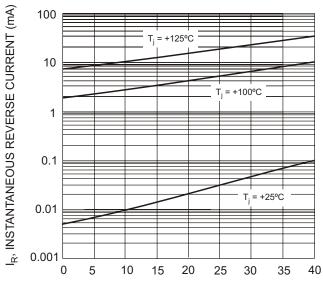
YWW = Date code marking

Y = Last digit of year ex: 2 for 2002

WW = Week code 01 to 52



 $V_{\text{F}}$ , INSTANTANEOUS FORWARD VOLTAGE (mV) Fig. 1 Typical Forward Characteristics (per element)



V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 2 Typical Reverse Characteristics (Per Element)



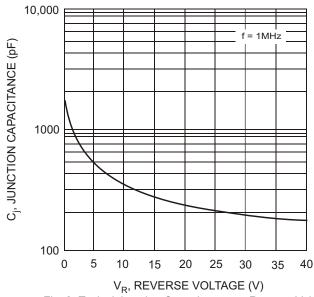


Fig. 3 Typical Junction Capacitance vs. Reverse Voltage

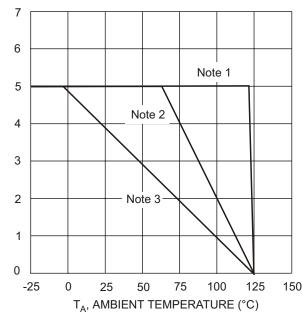
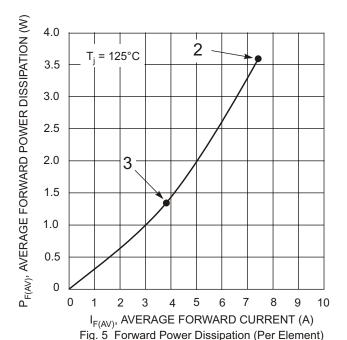


Fig. 4 DC Forward Current Derating (Per Element)



Notes:

- 1.  $T_A = T_{SOLDERING\ POINT},\ R_{\theta JC} = 2.43^{\circ}C/W,\ R_{\theta CA} = 0^{\circ}C/W.$
- 2. Device mounted on GETEK substrate, 2"x2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0".  $R_{\theta JA}$  in range of 15-30°C/W.

I<sub>F(AV)</sub>, AVERAGE FORWARD CURRENT (A)

 Device mounted on FR-4 substrate, 2"x2", 2 oz. copper, single-sided, pad layout as per Diodes Inc. suggested pad layout document AP02001 which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. R<sub>θJA</sub> in range of 60-75°C/W.